

HMA121A

HMA121B

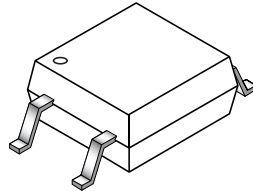
HMA121C

DESCRIPTION

The HMA121X series consists of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a compact 4-pin mini-flat package. The lead pitch is 2.54 mm.

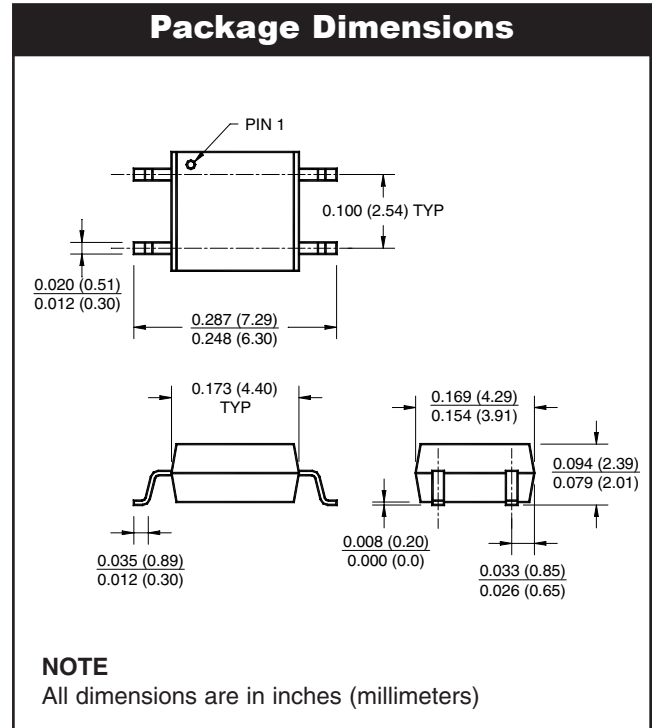
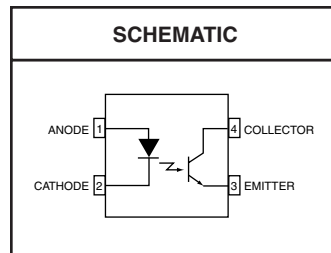
FEATURES

- Compact 4-pin package (2.4 mm maximum standoff height)
- Current Transfer Ratio: in selected groups
HMA121A: 100-300%
HMA121B: 50-150%
HMA121C: 100-200%
- Available in tape and reel quantities of 500 and 2500.
- Applicable to Infrared Ray reflow (230°C max, 30 seconds.)
- U.L. (File # E90700), CSA (82858) and BSI (8611/8612) certified
- VDE certified (option V)
- Creepage ≥ 5 mm, typical 5.2 mm
- Clearance ≥ 5 mm, typical 5.2 mm



APPLICATIONS

- Digital logic inputs
- Microprocessor inputs
- Power supply monitor
- Twisted pair line receiver
- Telephone line receiver



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise specified)			
Parameter	Symbol	Value	Units
TOTAL PACKAGE			
Storage Temperature	T_{STG}	-55 to +150	$^\circ\text{C}$
Operating Temperature	T_{OPR}	-55 to +100	$^\circ\text{C}$
EMITTER			
Continuous Forward Current	I_F (avg)	50	mA
Peak Forward Current (1 μs pulse, 300 pps.)	I_F (pk)	1	A
Reverse Input Voltage	V_R	6	V
Power Dissipation	P_D	70	mW
Derate linearly (above 25°C)		0.65	mW/ $^\circ\text{C}$
DETECTOR			
Continuous Collector Current		80	mA
Power Dissipation	P_D	150	mW
Derate linearly (above 25°C)		2.0	mW/ $^\circ\text{C}$
Collector-Emitter Voltage	V_{CEO}	80	V
Emitter-Collector Voltage	V_{ECO}	7	V

HMA121A

HMA121B

HMA121C

ELECTRICAL CHARACTERISTICS (T _A = 25°C)							
INDIVIDUAL COMPONENT CHARACTERISTICS							
Parameter	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
EMITTER							
Forward Voltage	(I _F = 10 mA)	V _F	ALL	1.0		1.3	V
Reverse Current	(V _R = 5 V)	I _R	ALL			5	μA
DETECTOR							
Breakdown Voltage Collector to Emitter	(I _C = 1 mA, I _F = 0)	BV _{CEO}	ALL	80			V
Emitter to Collector	(I _E = 100 μA, I _F = 0)	BV _{ECO}	All	7			
Collector Dark Current	(V _{CE} = 40 V, I _F = 0)	I _{CEO}	All			100	nA
Capacitance	(V _{CE} = 0 V, f = 1 MHz)	C _{CE}	All		10		pF

TRANSFER CHARACTERISTICS (T _A = 25°C)							
Characteristic	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
DC Current Transfer Ratio	(I _F = 5 mA, V _{CE} = 5 V)	CTR	HMA121A	100		300	%
			HMA121B	50		150	
			HMA121C	100		200	
Saturation Voltage	(I _F = 8 mA, I _C = 2.4 mA)	V _{CE (SAT)}	ALL			0.4	V
Rise Time (Non-Saturated)	(I _C = 2 mA, V _{CE} = 5 V) (R _L = 100Ω)	t _r	ALL		3		μs
Fall Time (Non-Saturated)	(I _C = 2 mA, V _{CE} = 5 V) (R _L = 100Ω)	t _f	ALL		3		

ISOLATION CHARACTERISTICS							
Characteristic	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
Steady State Isolation Voltage	(1 Minute)	V _{ISO}	All	3750			VRMS

** All typicals at T_A = 25°C

TYPICAL PERFORMANCE CURVES

Fig. 1 Forward Current vs. Forward Voltage

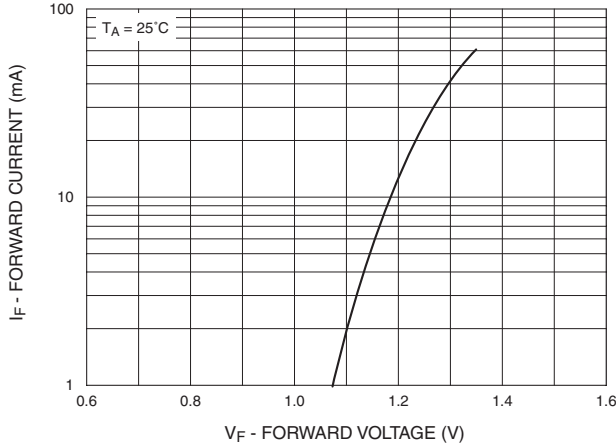


Fig. 2 Collector Current vs. Forward Current

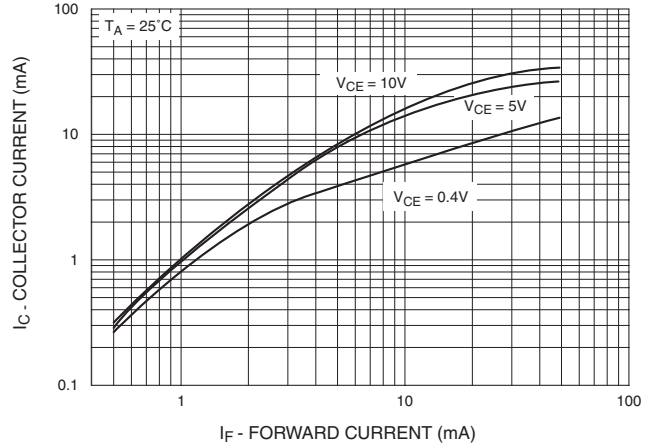


Fig. 3 Current Transfer Ratio vs. Forward Current

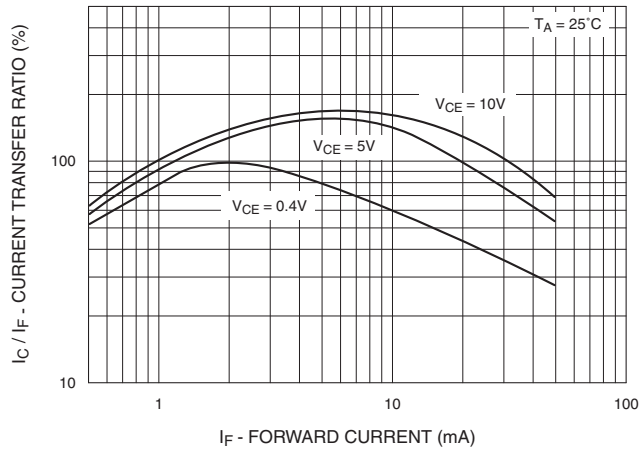


Fig. 4 Collector Current vs. Temperature

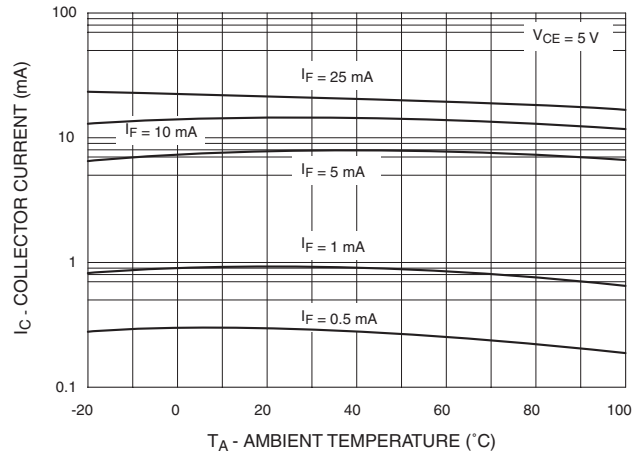
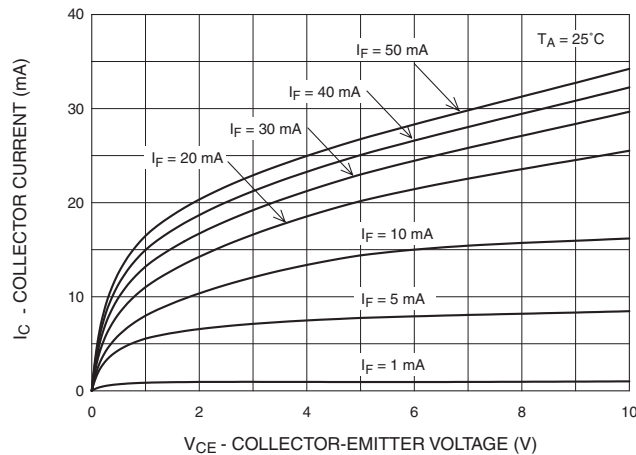


Fig. 5 Collector Current vs. Collector-Emitter Voltage



HMA121A

HMA121B

HMA121C

Fig. 6 Collector Current vs. Collector-Emitter Voltage

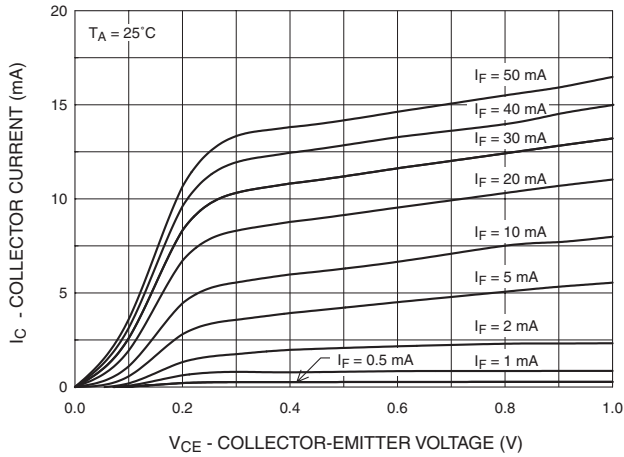


Fig. 7 Collector Dark Current vs. Temperature

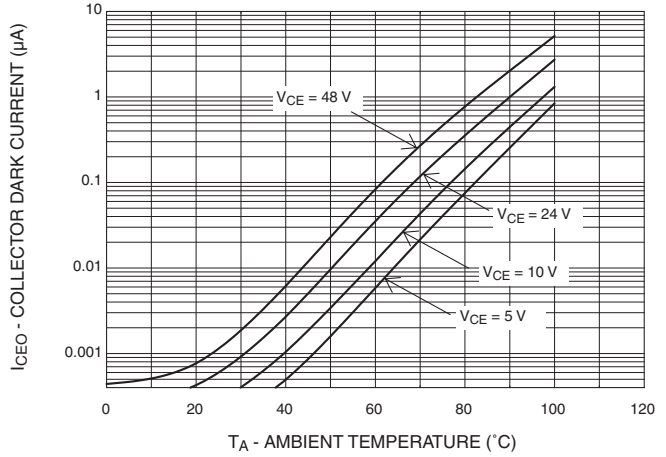


Fig. 8 Switching Time vs. Load Resistance

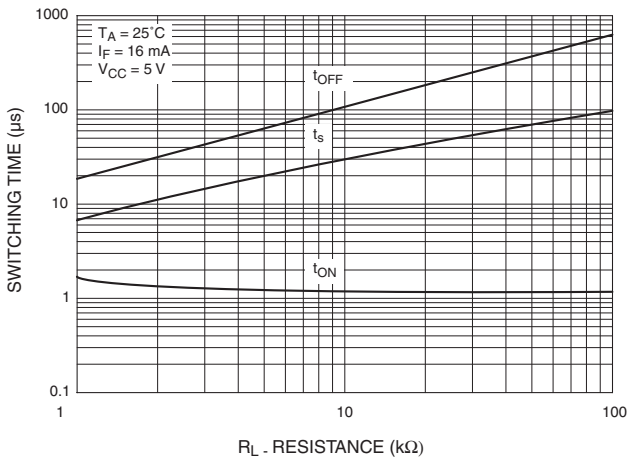
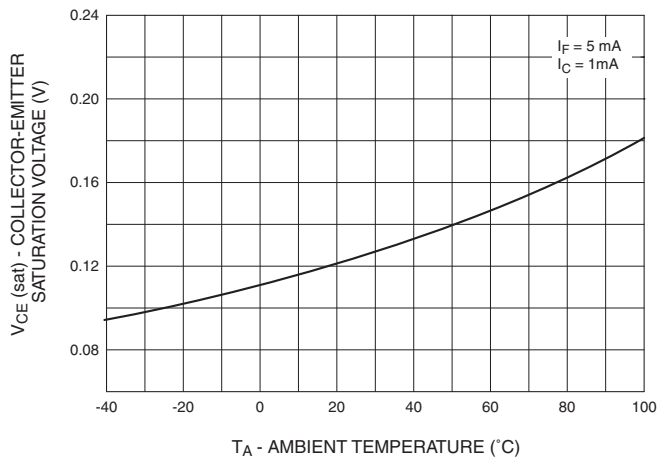


Fig. 9 Collector-Emitter Saturation Voltage vs. Temperature



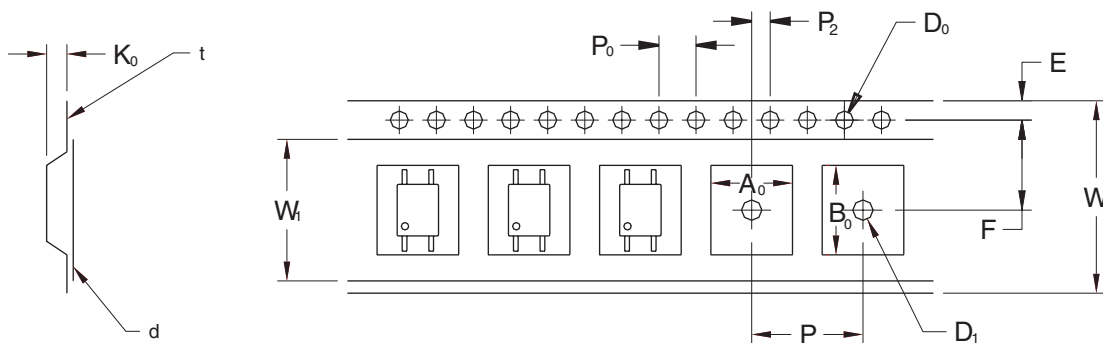
HMA121A

HMA121B

HMA121C

ORDERING INFORMATION

Option	Description
R1	Tape and Reel (500 Units)
R2	Tape and Reel (2500 Units)

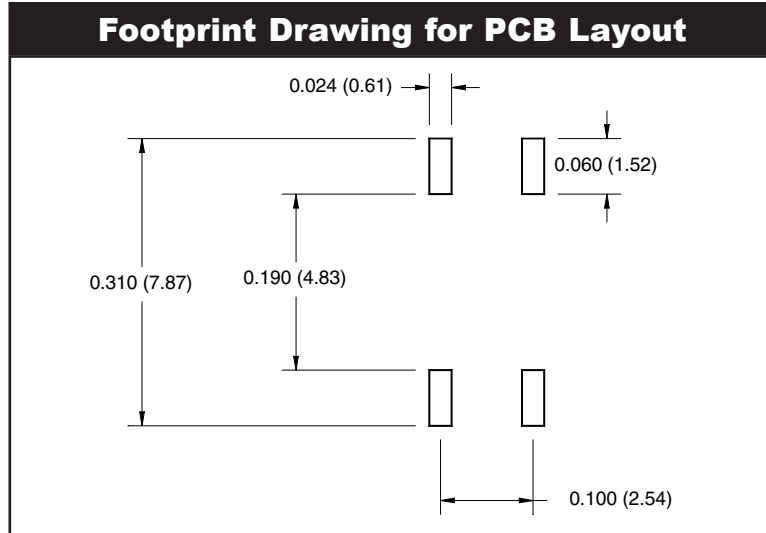


Description		Symbol	2.54 Pitch Dimensions (mm)
Tape Width		W	12.00±0.4
Tape Thickness		t	0.30±0.20
Sprocket Hole Pitch		P_0	4.00±0.20
Sprocket Hole Dia.		D_0	1.55±0.20
Sprocket Hole Location		E	1.75±0.20
Pocket Location		F	5.50±0.20
		P_2	2.00±0.20
Pocket Pitch		P	8.00±0.20
Pocket Dimension		A_0	4.40±0.20
		B_0	7.30±0.20
		K_0	2.30±0.20
Pocket Hole Dia.		D_1	1.55±0.20
Cover Tape Width		W_t	9.20
Cover Tape Thickness		d	0.065±0.02
Max. Component Rotation or Tilt			20° max
Devices Per Reel	R1		500
	R2		2500
Reel Diameter	R1		178 mm (7")
	R2		330 mm (13")

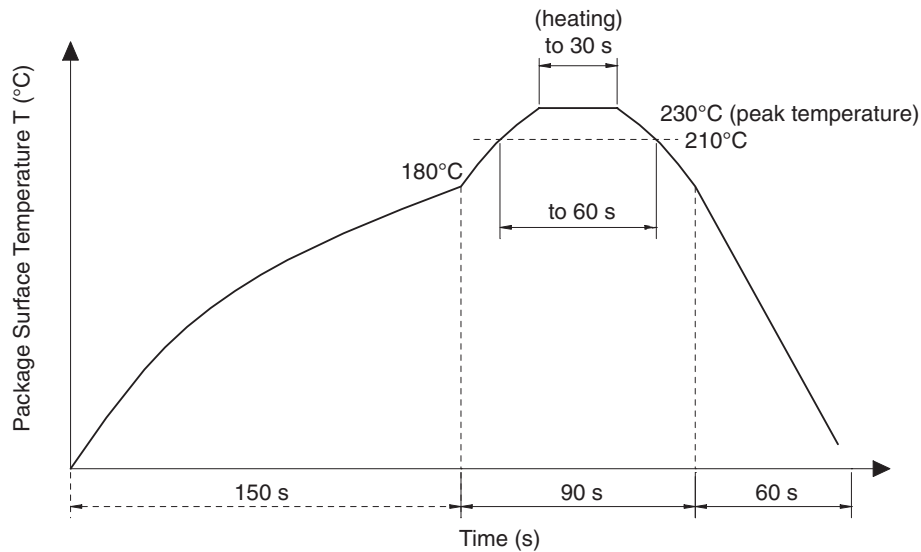
HMA121A

HMA121B

HMA121C



Recommended Infrared Reflow Soldering Profile



- Peak reflow temperature: 230°C (package surface temperature) for 30 seconds
- Time of temperature higher than 210°C: 60 seconds or less
- One time soldering reflow is recommended

HMA121A

HMA121B

HMA121C

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